## NSN 5961-01-394-4895

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-394-4895 **Inclosure Material:** Ceramic **Overall Length:** Between 0.140 inches and 0.163 inches **Overall Diameter:** Between 0.118 inches and 0.124 inches **Mounting Facility Quantity:** 2 **Mounting Method:** Compression **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 120.0 breakover voltage, dc and 180.0 breakover voltage, dc **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 200.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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